





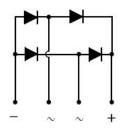
# GBPC50005(W) THRU GBPC5010(W) SINGLE PHASE 50 AMP GLASS PASSIVATED BRIDGE RECTIFIER



#### **Features**

- Glass passivated die construction
- Low forward voltage drop
- · High current capability
- High surge current capability
- Plastic material-UL flammability 94V-0
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Circuit Diagram**



#### **Mechanical Data**

- Case: GBPC/GBPC-W, molded plastic
- Terminals: plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on case
- Mounting position: Any
- Lead Free: For RoHS / Lead Free Version

#### Maximum Ratings: @T<sub>A</sub>=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Type number	Symbol	GBPC 50005(W)	GBPC 5001(W)	GBPC 5002(W)	GBPC 5004(W)	GBPC 5006(W)	GBPC 5008(W)	GBPC 5010(W)	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @ T <sub>A</sub> =55°C	lo	50						А	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	500						А	

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#### **Electrical Characteristics:**

Type number	Symbol	GBPC 50005(W)	GBPC 5001(W)	GBPC 5002(W)	GBPC 5004(W)		GBPC 5008(W)	GBPC 5010(W)	
Forward Voltage per element @I⊧=25.0A	VF	1.1						V	
Peak Reverse Current @T <sub>A</sub> =25℃ At Rated DC Blocking Voltage @T <sub>A</sub> =125℃	I <sub>R</sub>	10 500						μA	
Typical Junction Capacitance (Note 2)	CJ	300						рF	

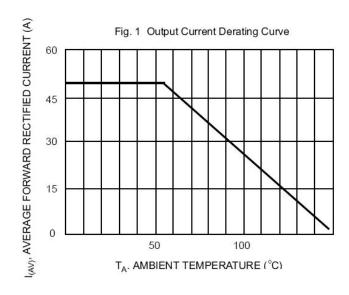
<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

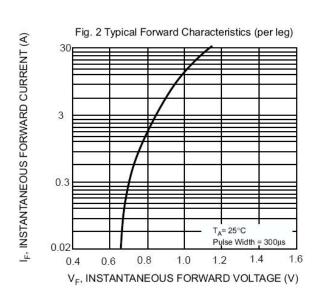
#### **Thermal-Mechanical Specifications:**

Type number	Symbol	GBPC 50005(W)		GBPC 5002(W)	GBPC 5004(W)	GBPC 5006(W)	GBPC 5008(W)	GBPC 5010(W)	Units
Typical Thermal Resistance Junction to Lead	R <sub>θJL</sub>	2.2							
Junction Temperature	TJ	-55 to +150						°C	
Storage Temperature Range	T <sub>STG</sub>	-55 to +150						°C	

Note: 1. Mounted on glass epoxy PC board with 1.3mm² solder pad. 2.Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

# **Ratings and Characteristics Curves**



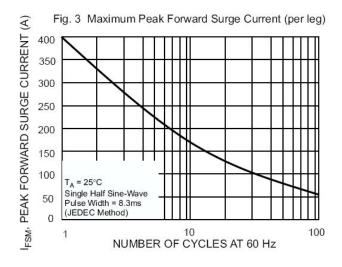


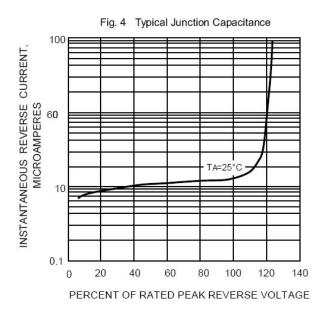
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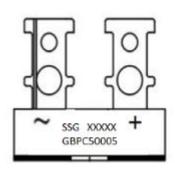


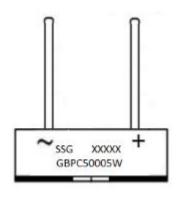
# **Ordering Information**

Device	Package	Plating	Shipping		
GBPC50005-GBPC5010	GBPC(Pb-Free)	Pure Sn	50pcs / box		
GBPC50005W-GBPC5010W	GBPC-W(Pb-Free)	Pure Sn	50pcs / box		

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

#### **Marking Diagram**





Where XXXXX is YYWWL

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

 GBPC50005/W
 = Type Number

Cautions: Molding resin Epoxy resin UL:94V-0

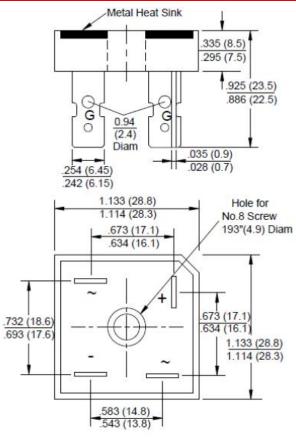
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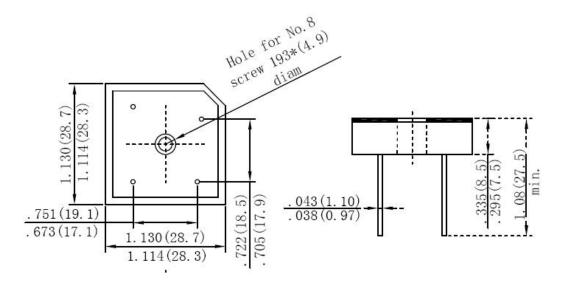




### **Mechanical Dimensions GBPC (Inches/Millimeters)**



# **Mechanical Dimensions GBPC-W (Inches/Millimeters)**



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GBPC50005(W) THRU GBPC5010(W)

# Technical Data Data Sheet N1852. Rev. A





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